

R-C Thermal Model Parameters

DESCRIPTION

The parametric values in the R-C thermal model have been derived using curve-fitting techniques. R-C values for the electrical circuit in the Foster/tank and Cauer/filter configurations are included. When implemented in P-SPICE, these values have matching characteristic curves to the single-pulse transient thermal impedance curves for the MOSFET.

These RC values can be used in the P-SPICE simulation to evaluate the thermal behavior of the MOSFET junction temperature under a defined power profile. These techniques are described in application note AN609, "Thermal Simulation of Power MOSFETs on the P-SPICE Platform".

R-C THERMAL MODEL FOR TANK CONFIGURATION



R-C VALUES FOR TANK CONFIGURATION			
THERMAL RESISTANCE (°C/W)			
Junction to	Ambient	Case	Foot
RT1	11.6896	322.3634 m	N/A
RT2	29.0173	151.4366 m	N/A
RT3	14.5773	4.6136	N/A
RT4	49.7158	4.4126	N/A
THERMAL CAPACITANCE (Joules/°C)			
Junction to	Ambient	Case	Foot
CT1	190.9854 u	1.1721 u	N/A
CT2	3.6354 m	11.1338 m	N/A
CT3	280.9408 m	81.8257 u	N/A
CT4	1.7157	301.4118 u	N/A

Note

N/A indicates not applicable

This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits.

R-C THERMAL MODEL FOR FILTER CONFIGURATION**R-C VALUES FOR FILTER CONFIGURATION**

THERMAL RESISTANCE (°C/W)			
Junction to	Ambient	Case	Foot
RF1	13.5612	4.5235	N/A
RF2	27.4850	3.8638	N/A
RF3	19.1865	99.5030 m	N/A
RF4	44.7673	1.0032	N/A
THERMAL CAPACITANCE (Joules/°C)			
Junction to	Ambient	Case	Foot
CF1	194.9020 u	40.9905 u	N/A
CF2	3.6294 m	141.3380 u	N/A
CF3	219.6482 m	778.5330 u	N/A
CF4	1.6974	318.3538 u	N/A

Note

N/A indicates not applicable

